**4th IFQMS Short Presentation Abstract Template**

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**Introduction**

This is the template of abstract of 3rd IFQMS Oral and Short Presentation Session. The length of abstract should be 1 page.

**Method**

Tables should be serially numbered as Table 1, Table 2, and so on, and Figures should be numbered as FIG. 1, FIG. 2 and so on [1]. The following is an example of figure and figure caption. The style of tables should be the Physical Review format.



FIG. 1. SEM image of the fabricated thin film on the Si substrate.

NOTE:

If this article involves Q-LEAP results, please include the following acknowledgement text.

“This work was supported by MEXT Q-LEAP Grant Number JPMXS01XXXXXXXX.”

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<https://www.qms.e.titech.ac.jp/hq_files/ifqms/kadaibango20.pdf>

**Reference**

1S. Schmitt, *Science*, volume, page (Year).

NOTE:

For the citation of books and conference proceedings, see Physical Review Style and Notation Guide.